Analog Power AM7480N

N-Channel 80-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

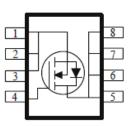
- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY					
V _{DS} (V)	I⊳(A)				
80	$30 @ V_{GS} = 10V$	12			
	40 @ V _{GS} = 4.5V	11			



FREE





ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)							
Parameter				Limit	Units		
Drain-Source Voltage				80	V		
Gate-Source Voltage				±20	V		
Continuous Drain Courset a		T _A =25°C	ı	12			
Continuous Drain Current ^a		T _A =70°C	I _D	9	Α		
Pulsed Drain Current ^b				60	'		
Continuous Source Current (Diode Conduction) a	I _S	6.5	Α				
Device Discipation 8		T _A =25°C	P _D	5	W		
Power Dissipation ^a		T _A =70°C	' D	3.2	VV		
Operating Junction and Storage Temperature Range				-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	35	°C/W			
IMAXIIIIUIII JUIICIIOII-IO-AIIIDIEIII	Steady State		65	C/VV			

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}$			1 uA		
Zero Gate Voltage Brain Current	I _{DSS}	$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	6			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_D = 9.6 \text{ A}$			30	mΩ	
Dialii-Source Off-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 8.8 \text{ A}$			40	11122	
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 9.6 \text{ A}$		40		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 3.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.72		V	
		Dynamic					
Total Gate Charge	Q_g			16			
Gate-Source Charge	Q_{gs}	$V_{DS} = 40 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 9.6 \text{ A}$		5.8		nC	
Gate-Drain Charge	Q_{gd}			8.4			
Turn-On Delay Time	t _{d(on)}			6			
Rise Time	t _r	$V_{DS} = 40 \text{ V}, R_L = 4.2 \Omega, I_D = 9.6 \text{ A},$		10		ns	
Turn-Off Delay Time	$t_{d(off)}$	V_{GEN} = 10 V, R_{GEN} = 6 Ω		45			
Fall Time	t _f			17			
Input Capacitance	C _{iss}			1216			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		154		pF	
Reverse Transfer Capacitance	C _{rss}			131			

Notes

- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

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Typical Electrical Characteristics

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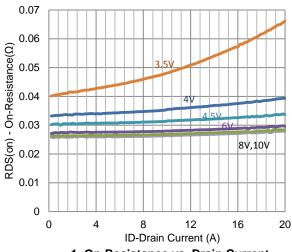
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16

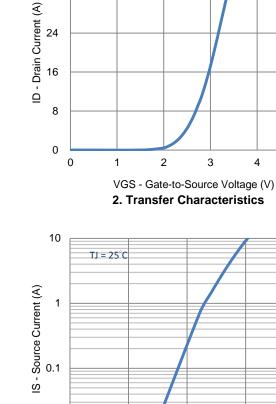
0.01

0.2

TJ = 25°¢



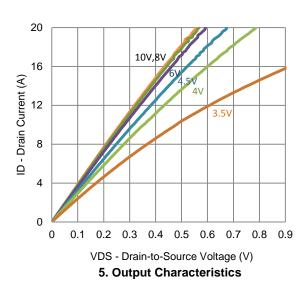
1. On-Resistance vs. Drain Current



0.4

 $TJ = 25^{\circ}C$

ID = 9.6A



VGS - Gate-to-Source Voltage (V)

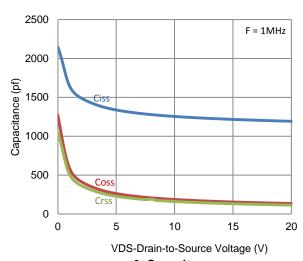
3. On-Resistance vs. Gate-to-Source Voltage

4. Drain-to-Source Forward Voltage

0.6

VSD - Source-to-Drain Voltage (V)

5



0.1

0.09

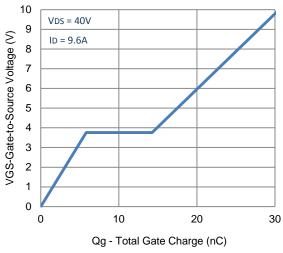
SDS(ou) - Ou-Resistance(Ω) 0.05 - 0.05 0.00 - 0.03 0.00 2

0.01

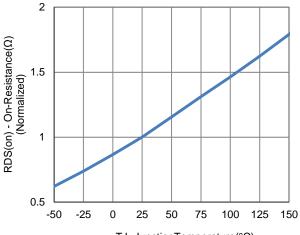
0

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Typical Electrical Characteristics

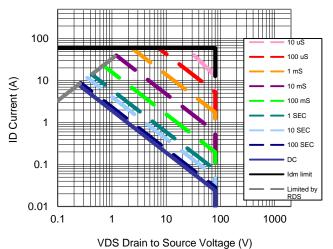




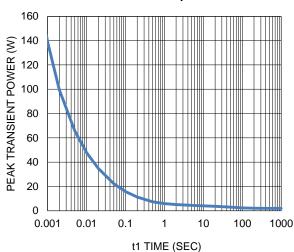


TJ -JunctionTemperature(°C)

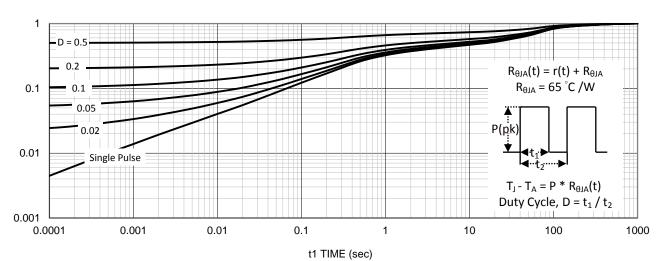




9. Safe Operating Area



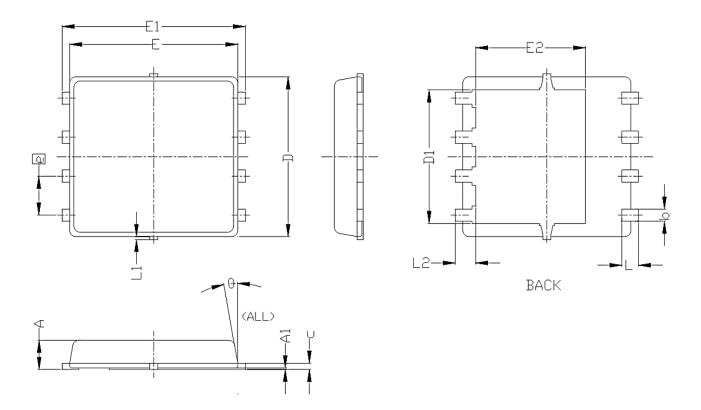
10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

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Package Information



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
STMBULS	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.85	0.95	1.00	0.033	0.037	0.039	
Al	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
с	0.15	0.20	0. 25	0.006	0.008	0.010	
D	5. 20 BSC			0. 205 BSC			
D1	4. 35 BSC			0. 171 BSC			
E	5. 55 BSC 0. 219 B				0.219 BSC		
E1	6. 05 BSC			0. 238 BSC			
E2	3. 62 BSC			0. 143 BSC			
e	1. 27 BSC			0.050 BSC			
L	0.45	0.55	0.65	0.018	0.022	0.026	
L1	0		0.15	0		0.006	
L2	0.68 REF			0. 027 REF			
θ	0°		10°	0°		10°	